

Low Input Current, Phototransistor Output, SOP-4, Mini-Flat Package



I179089



FEATURES

- Operating temperature from - 55 °C to + 110 °C
- SOP-4 mini-flat package
- Isolation test voltage, 3750 V_{RMS}
- Low saturation voltage
- Fast switching times
- Low coupling capacitance
- End-stackable, 0.100" (2.54 mm) spacing
- CTR range 40 % to 600 %, I_F = 5 mA
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



DESCRIPTION

The 110 °C rated VOM617A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin 100 mil lead pitch miniflat package. It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

These coupling devices are designed for signal transmission between two electrically separated circuits.

AGENCY APPROVALS

(All parts are certified under base model VOM617A)

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065 and EN 60950-1
- CQC GB8898-2011, GB4943.1-2001

APPLICATIONS

- PLCs
- Telecommunication
- Lighting control system
- Solar inverters
- AC drives

ORDERING INFORMATION



| AGENCY CERTIFIED/ PACKAGE | CTR (%) | | | | | | | |
|------------------------------|---------------|----------------|----------------|----------------|----------------|----------------|----------------|----------------|
| | 5 mA | | | | | | | |
| UL, cUL, FIMKO, CQC | 50 to 600 | 63 to 125 | 100 to 200 | 160 to 320 | 250 to 500 | 80 to 160 | 130 to 260 | 200 to 400 |
| SOP-4, mini-flat | VOM617AT | VOM617A-2T | VOM617A-3T | VOM617A-4T | VOM617A-6T | VOM617A-7T | VOM617A-8T | VOM617A-9T |
| VDE, UL, cUL, FIMKO, CQC | 50 to 600 | 63 to 125 | 100 to 200 | 160 to 320 | 250 to 500 | 80 to 160 | 130 to 260 | 200 to 400 |
| SOP-4, mini-flat | VOM617A-X001T | VOM617A-2X001T | VOM617A-3X001T | VOM617A-4X001T | VOM617A-6X001T | VOM617A-7X001T | VOM617A-8X001T | VOM617A-9X001T |

| ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | |
|--|----------------------------------|------------|---------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT | | | | |
| DC forward current | | I_F | 60 | mA |
| Reverse voltage | | V_R | 6 | V |
| Power dissipation | | P_{diss} | 70 | mW |
| Surge forward current | $t_p \leq 10\text{ }\mu\text{s}$ | I_{FSM} | 2.5 | A |
| OUTPUT | | | | |
| Collector emitter voltage | | V_{CEO} | 80 | V |
| Emitter collector voltage | | V_{ECO} | 7 | V |
| Collector current | | I_C | 50 | mA |
| | $t_p \leq 1\text{ ms}$ | | 100 | mA |
| Power dissipation | | P_{diss} | 150 | mW |
| COUPLER | | | | |
| Isolation test voltage between emitter and detector | $t = 1\text{ min}$ | V_{ISO} | 3750 | V_{RMS} |
| Total power dissipation | | P_{tot} | 170 | mW |
| Operating temperature range | | T_{amb} | - 55 to + 110 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | - 55 to + 150 | $^{\circ}\text{C}$ |
| Junction temperature | | T_j | 125 | $^{\circ}\text{C}$ |
| Soldering temperature ⁽¹⁾ | | T_{sld} | 260 | $^{\circ}\text{C}$ |

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ See "Assembly Instructions" for surface mounted devices (www.vishay.com/doc?80054).



Fig. 1 - Total Power Dissipation vs. Ambient Temperature



| ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|--|--|-------------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| INPUT | | | | | | |
| Forward voltage | $I_F = 5\text{ mA}$ | V_F | | 1.1 | 1.6 | V |
| Reverse current | $V_R = 6\text{ V}$ | I_R | | 0.01 | 10 | μA |
| Capacitance | $V_R = 0\text{ V}$, $f = 1\text{ MHz}$ | C_j | | 9 | | pF |
| OUTPUT | | | | | | |
| Collector emitter leakage current | $V_{CE} = 20\text{ V}$ | I_{CEO} | | 0.3 | 100 | nA |
| Collector emitter breakdown voltage | $I_C = 100\text{ }\mu\text{A}$ | BV_{CEO} | 80 | | | V |
| Emitter collector breakdown voltage | $I_E = 10\text{ }\mu\text{A}$ | BV_{ECO} | 7 | | | V |
| Collector emitter capacitance | $V_{CE} = 5\text{ V}$, $f = 1\text{ MHz}$ | C_{CE} | | 2.8 | | pF |
| COUPLER | | | | | | |
| Coupling capacitance | $f = 1\text{ MHz}$ | C_{IO} | | 0.3 | | pF |
| Collector emitter saturation voltage | $I_F = 10\text{ mA}$, $I_C = 2.5\text{ mA}$ | V_{CEsat} | | 0.12 | 0.4 | V |
| Cut-off frequency | $I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$ | f_{ctr} | | 110 | | kHz |

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | | |
|--|---|-----------|--------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I_C/I_F | $I_F = 5\text{ mA}$, $V_{CE} = 5\text{ V}$ | VOM617A | CTR | 50 | | 600 | % |
| | | VOM617A-2 | CTR | 63 | | 125 | % |
| | | VOM617A-3 | CTR | 100 | | 200 | % |
| | | VOM617A-4 | CTR | 160 | | 320 | % |
| | | VOM617A-6 | CTR | 250 | | 500 | % |
| | | VOM617A-7 | CTR | 80 | | 160 | % |
| | | VOM617A-8 | CTR | 130 | | 260 | % |
| | | VOM617A-9 | CTR | 200 | | 400 | % |

| SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|---|---|-----------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| NON-SATURATED | | | | | | |
| Rise and fall time | $I_C = 2\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$ | t_r | | 3 | | μs |
| Fall time | | t_f | | 3 | | μs |
| Turn-on time | | t_{on} | | 6 | | μs |
| Turn-off time | | t_{off} | | 4 | | μs |
| SATURATED | | | | | | |
| Rise and fall time | $I_F = 1.6\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 1.9\text{ k}\Omega$ | t_r | | 7 | | μs |
| Fall time | | t_f | | 12 | | μs |
| Turn-on time | | t_{on} | | 9 | | μs |
| Turn-off time | | t_{off} | | 15 | | μs |



Fig. 2 - Test Circuit



Fig. 3 - Test Circuit and Waveforms

| SAFETY AND INSULATION RATINGS | | | | |
|--|--|------------|------------|------------|
| PARAMETER | | SYMBOL | VALUE | UNIT |
| MAXIMUM SAFETY RATINGS | | | | |
| Output safety power | | P_{SO} | 300 | mW |
| Input safety current | | I_{si} | 200 | mW |
| Safety temperature | | T_S | 150 | °C |
| Comparative tracking index | | CTI | 175 | |
| INSULATION RATED PARAMETERS | | | | |
| Maximum withstanding isolation voltage | | V_{ISO} | 3750 | V_{RMS} |
| Maximum transient isolation voltage | | V_{IOTM} | 6000 | V_{peak} |
| Maximum repetitive peak isolation voltage | | V_{IORM} | 565 | V_{peak} |
| Insulation resistance | $T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$ | R_{IO} | 10^{12} | Ω |
| Isolation resistance | $T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$ | R_{IO} | 10^{11} | Ω |
| Climatic classification (according to IEC 68 part 1) | | | 55/110/21 | |
| Environment (pollution degree in accordance to DIN VDE 0109) | | | 2 | |
| Internal creepage | | | ≥ 5 | mm |
| External creepage | | | ≥ 5 | mm |
| Clearance | | | ≥ 5 | mm |
| Insulation thickness | | | ≥ 0.4 | mm |

Note

- As per DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)



Fig. 4 - Forward Voltage vs. Forward Current



Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)



Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)



Fig. 8 - Normalized Current Transfer Ratio (non-sat) vs. Ambient Temperature



Fig. 6 - Leakage Current vs. Ambient Temperature



Fig. 9 - Normalized Current Transfer Ratio (sat) vs. Ambient Temperature



Fig. 10 - Collector Emitter Voltage vs. Ambient Temperature (saturated)



Fig. 13 - F_{CTR} vs. Phase Angle



Fig. 11 - Normalized CTR (NS) vs. Forward Current



Fig. 14 - F_{CTR} vs. Collector Current



Fig. 12 - Normalized CTR (sat) vs. Forward Current



Fig. 15 - Switching Time vs. Load Resistance

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example of VOM617A-3X001T)



Notes

- Only option 1 is reflected in the package marking with the characters “X”.
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters



Fig. 16 - Reel Dimensions (3000 units per reel)



Fig. 17 - Tape Dimensions



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